

# GD54/74HC08, GD54/74HCT08

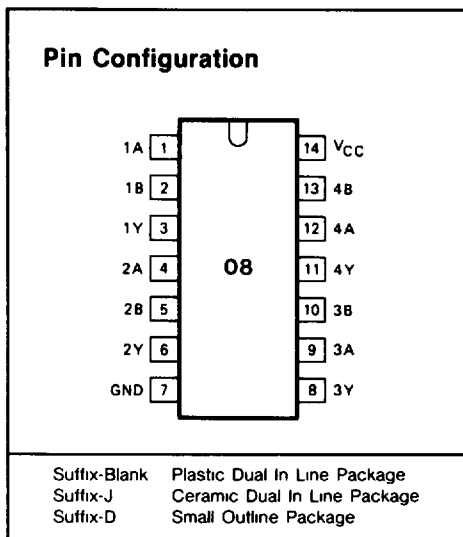
## QUAD 2-INPUT AND GATES

### General Description

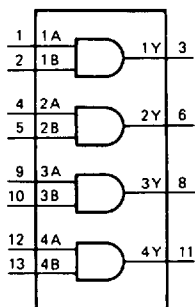
These devices are identical in pinout to the 54/74LS08. They contain four independent 2-input AND gates. These devices are characterized for operation over wide temperature ranges to meet industry and military specifications.

### Features

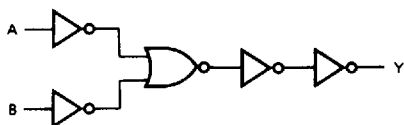
- Low Power consumption characteristic of CMOS devices
- Output drive capability: 10 LS TTL Loads Min.
- Operating speed superior to LS TTL
- Wide operating voltage range: for HC 2 to 6 volts  
for HCT 4.5 to 5.5 volts
- Low input current: 1 $\mu$ A Max.
- Low quiescent current: 20 $\mu$ A Max. (74HC)
- High noise immunity characteristic of CMOS
- Diode protection on all inputs



### Logic Symbol and Logic Diagram



### Function Table



INPUTS		OUTPUT
nA	nB	nY
L	L	L
L	H	L
H	L	L
H	H	H

H= HIGH voltage level  
L= LOW voltage level

Fig. 1 Logic symbol

Fig. 2 Logic diagram (one gate)

**Absolute Maximum Ratings**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CC}$	DC Supply voltage		-0.5	+7	V
$I_{IK}, I_{OK}$	DC input or output diode current	for $V_I < -0.5$ or $V_I > V_{CC} + 0.5V$		20	mA
$I_O$	DC output source or sink current	for $-0.5V < V_O < V_{CC} + 0.5V$		25	mA
$I_{CC}$	DC $V_{CC}$ or GND current			50	mA
$T_{stg}$	Storage temperature range		-65	150	°C
$P_D$	Power dissipation per package	above +70°C. derate linearly with 8mW/K		500	mW
$T_L$	Lead temperature	At distance 1/16 ± 1/32 in from case for 60 sec(CERAMIC) 10 sec(PLASTIC)		300 260	°C

**Recommended Operating Conditions**

CHARACTERISTIC	LIMITS		UNITS
	MIN	MAX.	
Supply-Voltage Range $V_{CC}$ : GD54/74HC Types GD54/74HCT Types	2 4.5	6 5.5	V
DC Input or Output Voltage $V_I, V_O$	0	$V_{CC}$	V
Operating Temperature $T_A$ : GD74 Types GD54 Types	-40 -55	+85 +125	°C
Input Rise and Fall times $t_r, t_f$ : GD54/74HC Types at 2V at 4.5V at 6V GD54/74HCT Types at 4.5V		1000 500 400 500	ns

DC Electrical Characteristics for HC

SYMBOL	PARAMETER	TEST CONDITION	V <sub>CC</sub> (V)	T <sub>A</sub> =25°C			GD74HC08		GD54HC08		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.		
V <sub>IH</sub>	HIGH level input Voltage		2.0	1.5			1.5		1.5		V	
			4.5	3.15		3.15		3.15				
			6.0	4.2		4.2		4.2				
V <sub>IL</sub>	LOW level input voltage		2.0			0.3		0.3		0.3	V	
			4.5			0.9		0.9				
			6.0			1.2		1.2				
V <sub>OH</sub>	HIGH level output voltage	V <sub>IN</sub> =V <sub>IH</sub>	I <sub>OH</sub> =-20μA	2.0	1.9	2.0		1.9		1.9	V	
				4.5	4.4	4.5		4.4		4.4		
				6.0	5.9	6.0		5.9		5.9		
		or V <sub>IL</sub>	I <sub>OH</sub> =-4mA I <sub>OH</sub> =-5.2mA	4.5	3.98	4.3		3.84		3.7		
				6.0	5.48	5.2		5.34		5.2		
V <sub>OL</sub>	LOW level output voltage	V <sub>IN</sub> =V <sub>IH</sub>	I <sub>OL</sub> =20μA	2.0			0.1		0.1		V	
				4.5			0.1		0.1			
				6.0			0.1		0.1			
		or V <sub>IL</sub>	I <sub>OL</sub> =4mA I <sub>OL</sub> =5.2mA	4.5		0.17	0.26		0.33			0.4
				6.0		0.15	0.26		0.33			0.4
I <sub>IN</sub>	Input leakage Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	6.0			0.1		1.0		1.0	μA	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =V <sub>CC</sub> or GND I <sub>out</sub> =0μA	6.0			2		20		40	μA	

DC Electrical Characteristics for HCT

SYMBOL	PARAMETER	TEST CONDITION	V <sub>CC</sub> (V)	T <sub>A</sub> =25°C			GD74HCT08		GD54HCT08		UNIT	
				MIN	TYP.	MAX.	MIN	MAX.	MIN	MAX.		
V <sub>IH</sub>	HIGH level input Voltage		4.5								V	
			to 5.5	2.0			2.0		2.0			
V <sub>IL</sub>	LOW level input voltage		4.5								V	
			to 5.5			0.8		0.8		0.8		
V <sub>OH</sub>	HIGH level output voltage	V <sub>IN</sub> =V <sub>IH</sub>	I <sub>OH</sub> =-20μA	4.5	4.4	4.5		4.4		4.4	V	
				4.5	3.98	4.3		3.84		3.7		
				4.5								
		or V <sub>IL</sub>	I <sub>OH</sub> =-4mA	4.5	3.98	4.3		3.84		3.7		
				4.5								
				4.5								
V <sub>OL</sub>	LOW level output voltage	V <sub>IN</sub> =V <sub>IH</sub>	I <sub>OL</sub> =20μA	4.5			0.1		0.1		V	
				4.5			0.1		0.1			
				4.5			0.1		0.1			
		or V <sub>IL</sub>	I <sub>OL</sub> =4mA	4.5		0.17	0.26		0.33			0.4
				4.5		0.17	0.26		0.33			0.4
				4.5		0.17	0.26		0.33			0.4
I <sub>IN</sub>	Input leakage Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	5.5			0.1		1.0		1.0	μA	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =V <sub>CC</sub> or GND I <sub>out</sub> =0μA	5.5			2		20		40	μA	

AC Characteristics for HC:  $t_r=t_f=6ns$   $C_L=50pF$

SYMBOL	PARAMETER	V <sub>CC</sub> (V)	T <sub>A</sub> =25°C			GD74HC08		GD54HC08		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$t_{PLH}/$ $t_{PHL}$	Propagation delay time nA, nB to nY	2 0	25	90		115		135	ns	
		4 5	9	18		23		27		
		6 0	7	15		20		23		
$t_{TLH}/$ $t_{THL}$	Output transition time	2 0	19	75		95		110	ns	
		4 5	7	15		19		22		
		6 0	6	13		16		19		

AC Characteristics for HCT:  $t_r=t_f=6ns$   $C_L=50pF$

SYMBOL	PARAMETER	V <sub>CC</sub> (V)	T <sub>A</sub> =25°C			GD74HCT08		GD54HCT08		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$t_{PLH}/$ $t_{PHL}$	Propagation delay time nA, nB, to nY	4 5		14	24		30		36	ns
$t_{TLH}/$ $t_{THL}$	Output transition time	4 5		7	15		19		22	ns

AC Waveform

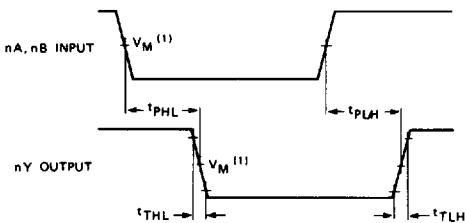


Fig. 3 Waveforms showing the input (nA, nB) to output (nY) propagation delays and the output transition times

Note to AC waveform

- (1) HC  $V_w=50\%$   $V_i=GND$  to  $V_{CC}$
- HCT  $V_w=1.3V$   $V_i=GND$  to  $3V$